



### 200V PNP HIGH VOLTAGE TRANSISTOR IN POWERDIS

### **Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5
- Case Material: Molded Plastic, "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 <a>3</a>
- Weight: 0.093 grams (Approximate)

#### **Features**

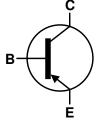
- BV<sub>CEO</sub> = -200V
- I<sub>C</sub> = -2A High Continuous Collector Current
- I<sub>CM</sub> = -5A Peak Collector Current
- P<sub>D</sub> up to 3.2W
- 43% smaller than SOT223; 60% smaller than TO252 (DPAK)
- Maximum height just 1.1mm
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTP03200BP5Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

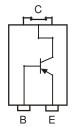
### Application

- DC DC Conversion
- Telecoms
- Power management





**Device Schematic** 



Top View Bottom View

Pin-Out Diagram

### **Ordering Information** (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXTP03200BP5Q-13	Automotive	DTP3200B	13	16	5,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

## Marking Information

DTP3200B

PowerDI®5



### Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-220	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-200	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-2	Α
Base Current	IB	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-5	Α

## Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ heta JA}$	39	°C/W
Power Dissipation (Note 6)	P <sub>D</sub>	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	75	°C/W
Power Dissipation (Note 7)	P <sub>D</sub>	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 7)	$R_{ heta JA}$	169	°C/W
Thermal Resistance, Junction to Lead (Note 8)	$R_{ heta JL}$	5.6	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

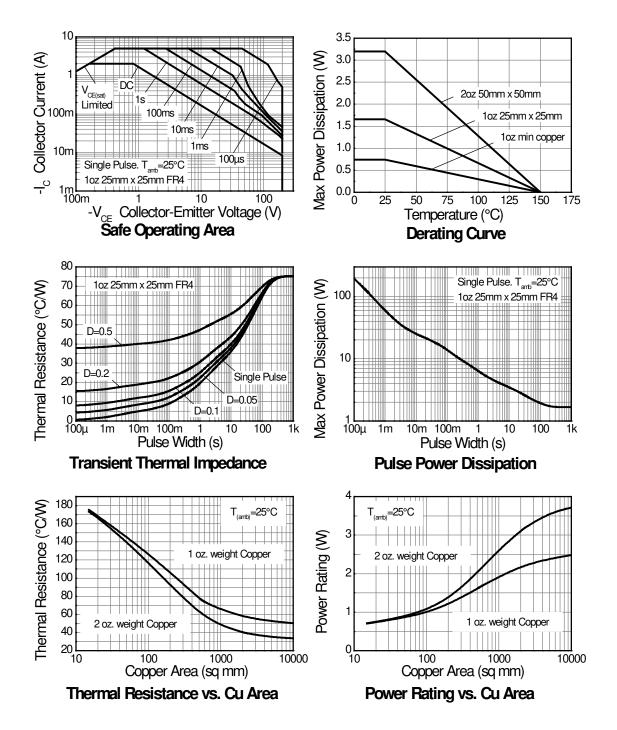
### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 5. Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
- Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 35mm x 35mm.
  Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
  Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.
  Thermal resistance from junction to solder-point (on the exposed collector pad).
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





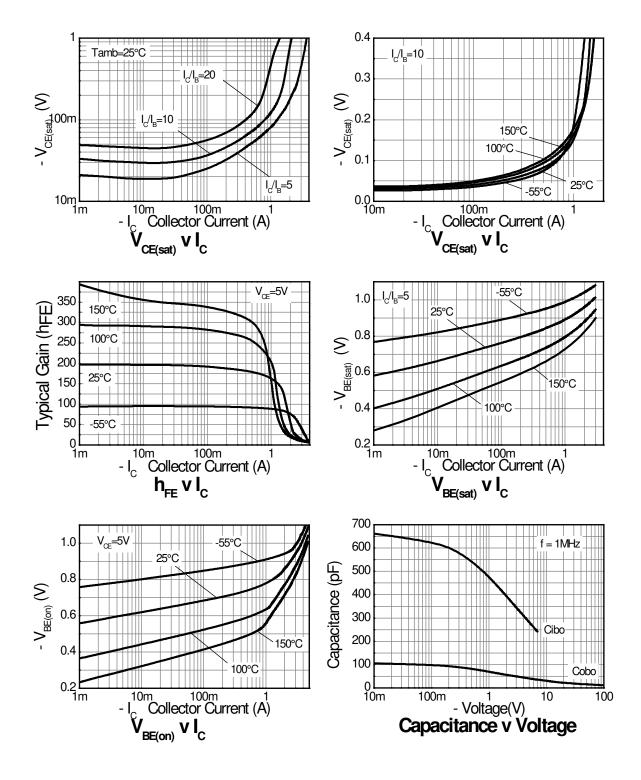
## Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-220	-245	=	V	$I_{C} = -100 \mu A$	
Collector-Emitter Breakdown Voltage (Note 10)	V <sub>(BR)CEO</sub>	-200	-225	_	V	I <sub>C</sub> = -10mA	
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-7	-8.4	_	V	$I_E = -100 \mu A$	
Collector Cutoff Current	lana	=	<1	-50	nA	V <sub>CB</sub> = -200V	
Collector Cuton Current	I <sub>CBO</sub>		-	-0.5	μΑ	$V_{CB} = -200V, T_A = +100^{\circ}C$	
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-10	nΑ	$V_{EB} = -6V$	
		_	-37	-50	mV	$I_C = -0.1A$ , $I_B = -10mA$	
Collector-Emitter Saturation Voltage (Note 10)	Vor. "	_	-130	-155		$I_C = -0.5A$ , $I_B = -25mA$	
Collector-Efficier Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	-	-135	-160	111 V	$I_C = -1A$ , $I_B = -100mA$	
		-	-180	-275		$I_C = -2A$ , $I_B = -400mA$	
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	-	-955	-1,100	mV	$I_C = -2A$ , $I_B = -400mA$	
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	-	-860	-1,000	mV	$V_{CE} = -5V, I_{C} = -2A$	
		100	195	=		$V_{CE} = -5V, I_{C} = -10mA$	
DC Current Gain (Note 10)	h <sub>FE</sub>	hee	100	170	300	_	$V_{CE} = -5V, I_{C} = -1A$
Do danent dam (Note 10)		20	50	=		$V_{CE} = -5V$ , $I_C = -2A$	
		=	5	-		$V_{CE} = -5V$ , $I_C = -5A$	
Transition Frequency	f <sub>T</sub>	_	105	_	MHz	$V_{CE} = -10V$ , $I_{C} = -100mA$ , $f = 50MHz$	
Output Capacitance	Cobo	-	31	=	рF	$V_{CB} = -10V$ , $f = 1MHz$	
Delay Time	t <sub>d</sub>	=	21	-	ns		
Rise Time	t <sub>r</sub>	-	18	=	ns	$V_{CC} = -50V, I_{C} = -1A,$	
Storage Time	ts	=	680	=	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$	
Fall Time	t <sub>f</sub>	=	75	=	ns		

Note: 10. Pulse Test: Pulse width  $\leq$ 300 $\mu$ s. Duty cycle  $\leq$ 2.0%.



# Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

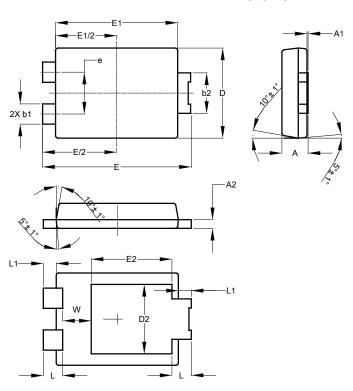




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5

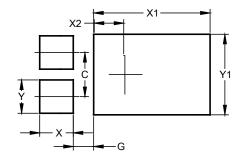


PowerDI5					
Dim	Min	Max	Тур		
Α	1.05	1.15	1.10		
A1	0.00	0.05			
A2	0.33	0.43	0.381		
b1	0.80	0.99	0.89		
b2	1.70	1.88	1.78		
D	3.90	4.05	3.966		
D2			3.054		
Е	6.40	6.60	6.51		
е			1.84		
E1	5.30	5.45	5.37		
E2	1	-	3.549		
L	0.75	0.95	0.85		
L1	0.50	0.65	0.57		
W	1.10	1.41	1.255		
All Dimensions in mm					

## **Suggested Pad Layout**

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$ 

#### PowerDI5



Dimensions	Value (in mm)		
С	1.840		
G	0.852		
Х	1.400		
X1	4.860		
X2	1.310		
Υ	1.390		
Y1	3.360		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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